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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: Shigeru HANEDA, et al.

SERIAL NUMBER: 10/671,492

GROUP: 2653

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EXAMINER: WATKO, JULIE ANNE

FOR: MAGNETO-RESISTANCE EFFECT ELEMENT WITH MAGNETISM SENSITIVE
REGION CONTROLLED BY VOLTAGE APPLIED TO GATE ELECTRODE

REQUEST TO CORRECT TITLE OF INVENTION

MAIL STOP ISSUE FEE
COMMISSIONER FOR PATENTS
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SIR:

In the matter of the above-identified application for patent, we hereby request correction of your records to reflect the correct title of the invention. The title of the invention should read as follows: **MAGNETO-RESISTANCE EFFECT ELEMENT WITH MAGNETISM SENSITIVE REGION CONTROLLED BY VOLTAGE APPLIED TO GATE ELECTRODE.**

Respectfully Submitted,

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